HD74AC02

Quad 2-Input NAND Gate

REJ03D0240–0200Z
(Previous ADE-205-356 (Z))
Rev.2.00
Jul.16.2004

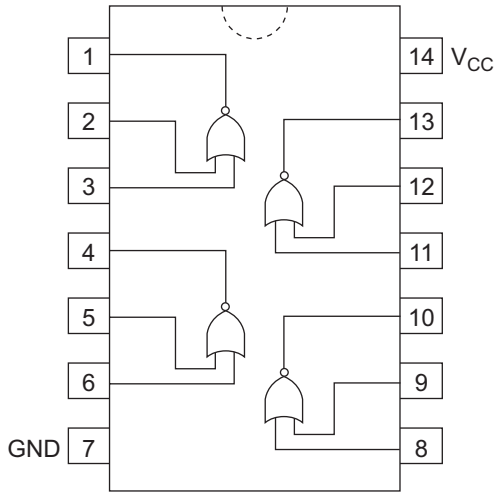
Features

- Outputs Source/Sink 24 mA
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74AC02P	DIP-14 pin	DP-14, -14AV	P	—
HD74AC02FPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74AC02RPEL	SOP-14 pin (JEDEC)	FP-14DNV	RP	EL (2,500 pcs/reel)
HD74AC02TELL	TSSOP-14 pin	TTP-14DV	T	ELL (2,000 pcs/reel)

Notes: 1. Please consult the sales office for the above package availability.
2. The packages with lead-free pins are distinguished from the conventional products by adding V at the end of the package code.

Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V_{CC}	–0.5 to 7	V	
DC input diode current	I_{IK}	–20	mA	V_I = –0.5V
		20	mA	V_I = Vcc+0.5V
DC input voltage	V_I	–0.5 to Vcc+0.5	V	
DC output diode current	I_{OK}	–50	mA	V_O = –0.5V
		50	mA	V_O = Vcc+0.5V
DC output voltage	V_O	–0.5 to Vcc+0.5	V	
DC output source or sink current	I_O	±50	mA	
DC V_{CC} or ground current per output pin	I_{CC}, I_{GND}	±50	mA	
Storage temperature	Tstg	–65 to +150	°C	

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V_{CC}	2 to 6	V	
Input and output voltage	V_I, V_O	0 to V_{CC}	V	
Operating temperature	Ta	–40 to +85	°C	
Input rise and fall time (except Schmitt inputs) V_{IN} 30% to 70% V_{CC}	tr, tf	8	ns/V	V_{CC} = 3.0V
				V_{CC} = 4.5 V
				V_{CC} = 5.5 V

DC Characteristics

Item	Sym-bol	Vcc (V)	Ta = 25°C			Ta = –40 to +85°C		Unit	Condition	
			min.	typ.	max.	min.	max.			
Input Voltage	V_{IH}	3.0	2.1	1.5	—	2.1	—	V	V_{OUT} = 0.1 V or V_{CC} –0.1 V	
		4.5	3.15	2.25	—	3.15	—			
		5.5	3.85	2.75	—	3.85	—			
	V_{IL}	3.0	—	1.50	0.9	—	0.9		V_{OUT} = 0.1 V or V_{CC} –0.1 V	
		4.5	—	2.25	1.35	—	1.35			
		5.5	—	2.75	1.65	—	1.65			
Output voltage	V_{OH}	3.0	2.9	2.99	—	2.9	—	V	V_{IN} = V_{IL} or V_{IH} I_{OUT} = –50 µA	
		4.5	4.4	4.49	—	4.4	—			
		5.5	5.4	5.49	—	5.4	—			
		3.0	2.58	—	—	2.48	—		V_{IN} = V_{IL} or V_{IH}	I_{OH} = –12 mA
		4.5	3.94	—	—	3.80	—			I_{OH} = –24 mA
		5.5	4.94	—	—	4.80	—			I_{OH} = –24 mA
	V_{OL}	3.0	—	0.002	0.1	—	0.1		V_{IN} = V_{IL} or V_{IH} I_{OUT} = 50 µA	
		4.5	—	0.001	0.1	—	0.1			
		5.5	—	0.001	0.1	—	0.1			
		3.0	—	—	0.32	—	0.37		V_{IN} = V_{IL} or V_{IH}	I_{OL} = 12 mA
		4.5	—	—	0.32	—	0.37			I_{OL} = 24 mA
		5.5	—	—	0.32	—	0.37			I_{OL} = 24 mA
Input leakage current	I_{IN}	5.5	—	—	±0.1	—	±1.0	µA	V_{IN} = V_{CC} or GND	
Dynamic output current*	I_{OLD}	5.5	—	—	—	86	—	mA	V_{OLD} = 1.1 V	
	I_{OHD}	5.5	—	—	—	–75	—	mA	V_{OHD} = 3.85 V	
Quiescent supply current	I_{CC}	5.5	—	—	4.0	—	40	µA	V_{IN} = V_{CC} or ground	

*Maximum test duration 2.0 ms, one output loaded at a time.

AC Characteristics

Item	Symbol	V_{CC} (V)*[1]	Ta = +25°C, C_L = 50 pF			Ta = –40°C to +85°C, C_L = 50 pF		Unit
			Min	Typ	Max	Min	Max	
Propagation delay	t_{PLH}	3.3	1.0	5.0	7.5	1.0	8.0	ns
		5.0	1.0	4.0	6.0	1.0	6.5	
Propagation delay	t_{PHL}	3.3	1.0	5.0	7.5	1.0	8.0	ns
		5.0	1.0	4.5	6.5	1.0	7.0	

Note: 1. Voltage Range 3.3 is 3.3 V ± 0.3 V
Voltage Range 5.0 is 5.0 V ± 0.5 V

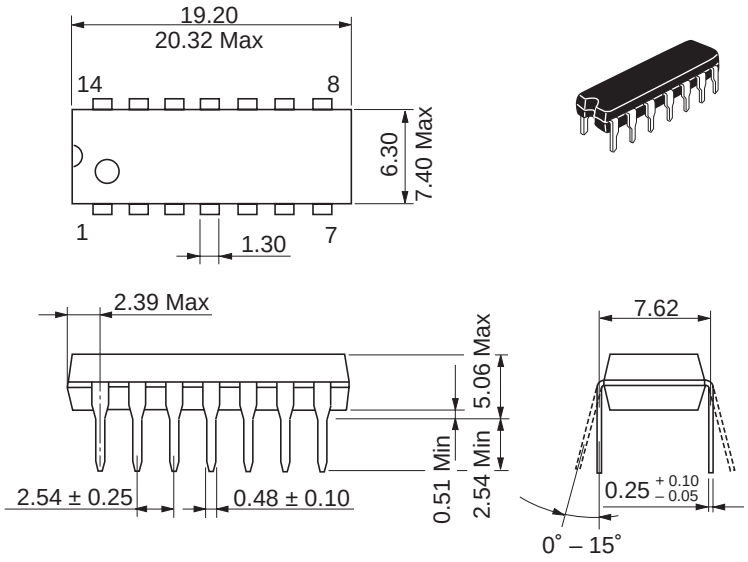
Capacitance

Item	Symbol	Typ	Unit	Condition
Input capacitance	C_{IN}	4.5	pF	V_{CC} = 5.5 V
Power dissipation capacitance	C_{PD}	30.0	pF	V_{CC} = 5.0 V

Package Dimensions

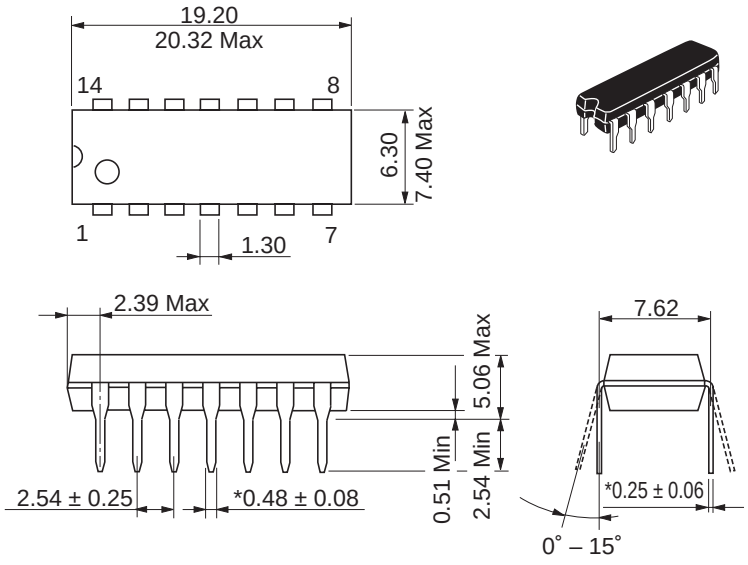
As of January, 2003

Unit: mm



Package Code	DP-14
JEDEC	Conforms
JEITA	Conforms
Mass (reference value)	0.97 g

Unit: mm

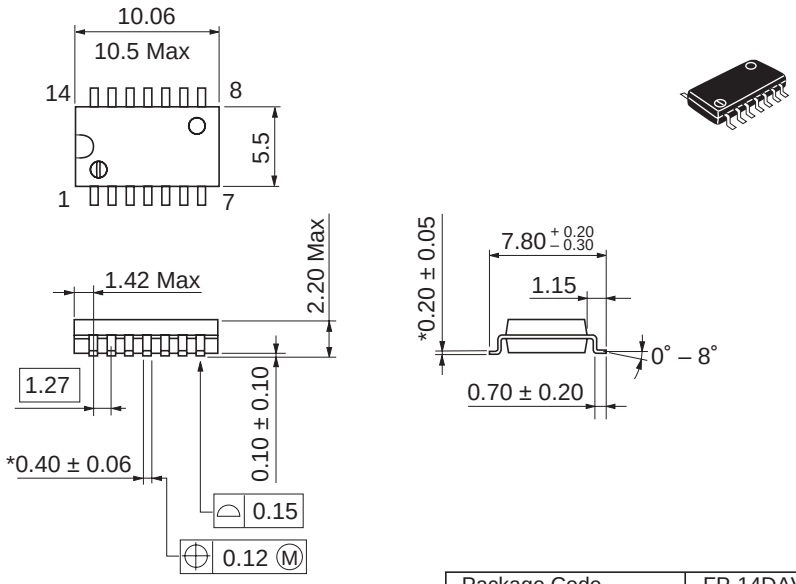


*NI/Pd/AU Plating

Package Code	DP-14AV
JEDEC	Conforms
JEITA	Conforms
Mass (reference value)	0.97 g

As of January, 2003

Unit: mm

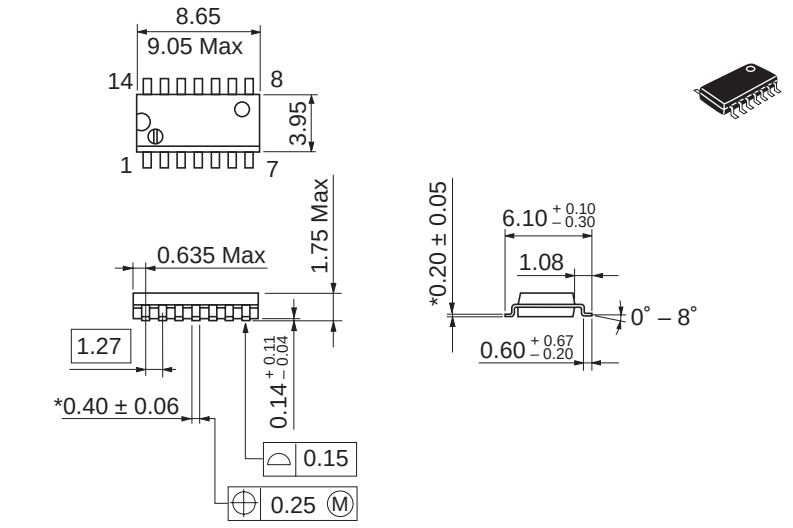


*Ni/Pd/Au plating

Package Code	FP-14DAV
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.23 g

As of January, 2003

Unit: mm

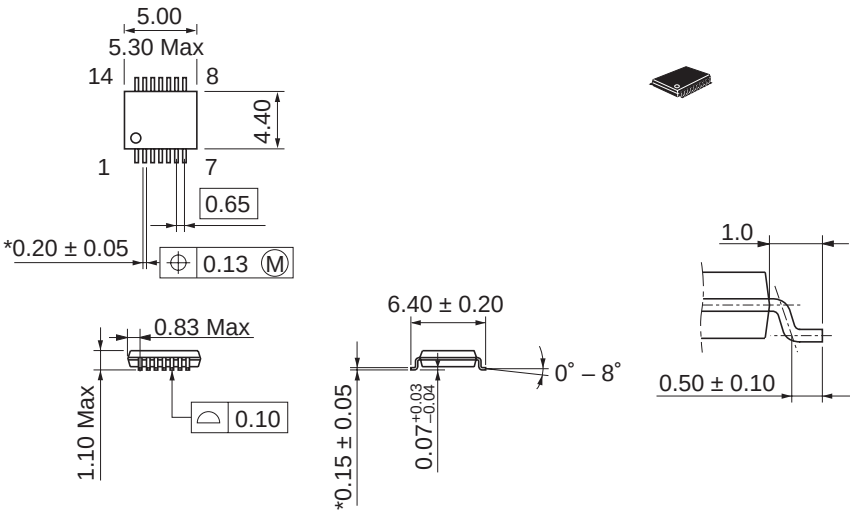


*Ni/Pd/Au plating

Package Code	FP-14DNV
JEDEC	Conforms
JEITA	Conforms
Mass (reference value)	0.13 g

As of January, 2003

Unit: mm



*Ni/Pd/Au plating

Package Code	TTP-14DV
JEDEC	—
JEITA	—
Mass (reference value)	0.05 g

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